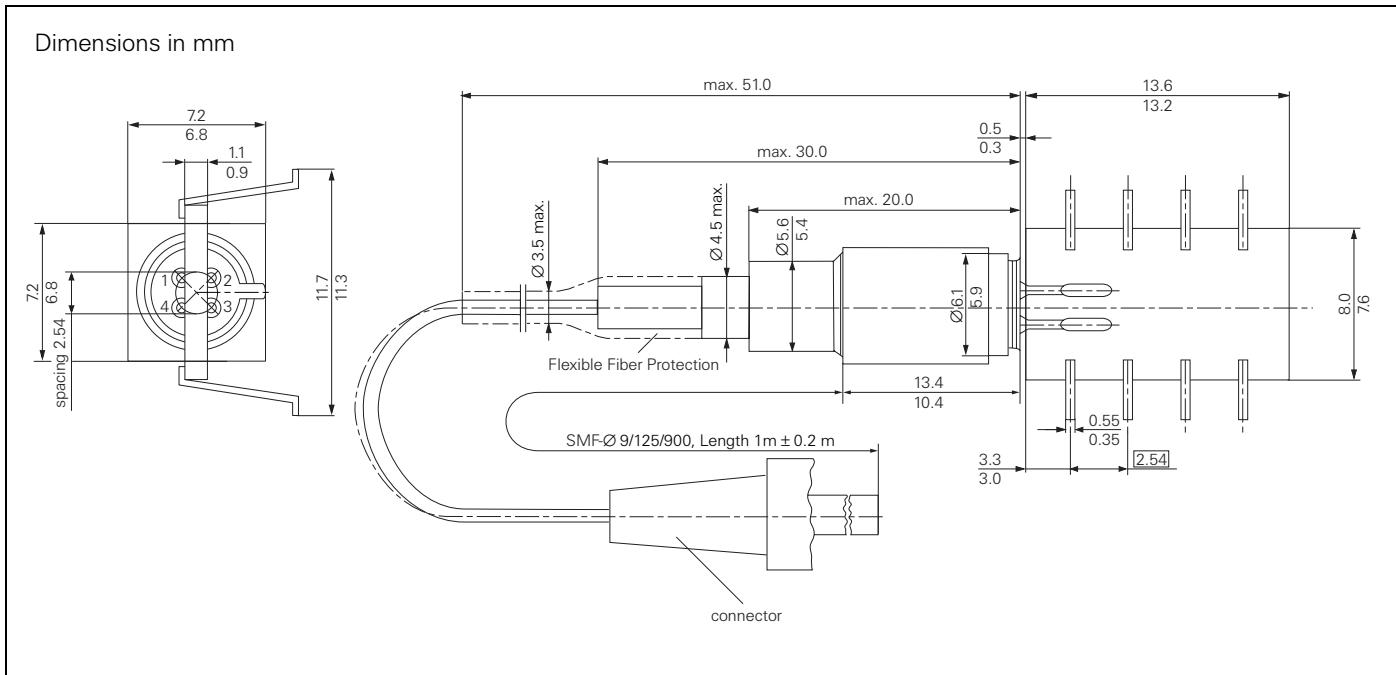


# SDH61008

## 1300nm DFB Laser in Coaxial Package with SM-Pigtail, High Power, with optical Isolator for 2.5 Gbit/s Application and adaption board to Mini-DL footprint

Target specification



### Absolute Maximum Ratings

Output power ratings refer to the SM fiber output. The operating temperature of the submount is identical to the case temperature

### Module

Operating case temperature ( $T_C$ ) .....	0 to +70°C
Storage temperature ( $T_{Stg}$ ) .....	-40 to +85°C
Soldering temperature <sup>(1)</sup> ( $T_S$ ) .....	260°C

### Laser Diode

Direct forward current ( $I_{Fmax}$ ) .....	120 mA
Radiant power CW ( $\Phi_e$ ) .....	4 mW
Reverse voltage ( $V_{Rmax}$ ) .....	2 V

### Monitor Diode

Reverse voltage ( $V_{Rmax}$ ) .....	10 V
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### Note

1.  $t_{max} = 10$  s, 2 mm distance from bottom edge of case

### DESCRIPTION

Designed for application in high-speed and long haul fiber-optic networks

Laser Diode with Multi-Quantum-Well and gain coupled structure

Suitable for bit rates up to 2.5 Gbit/s (STM-16) with optical isolator, without cooler

Ternary photodiode at rear mirror for monitoring and control of radiant power

Hermetically sealed subcomponent, similar to TO 18

SM Pigtail with optional flange

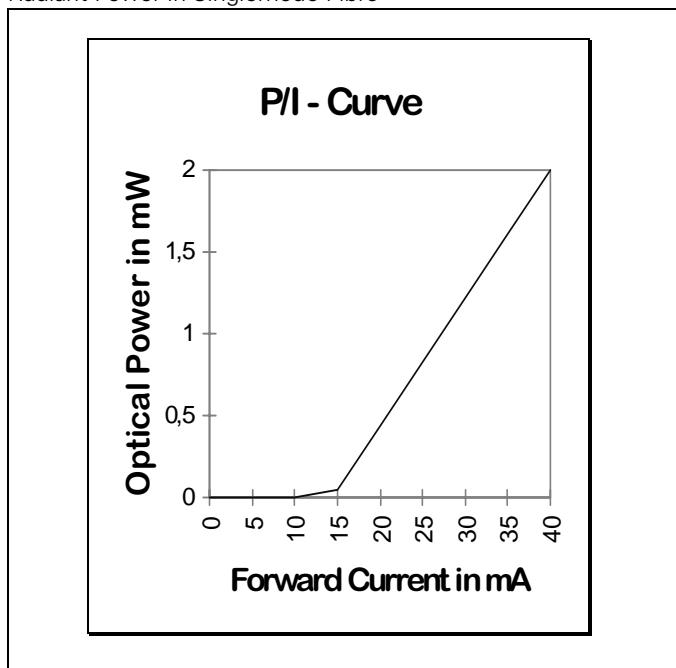
## Characteristics

All optical data refer to a coupled 10/125 $\mu\text{m}$  SM fiber,  $T_C = -25^\circ\text{C}$ .

<b>Laser diode</b>	<b>Symbol</b>	<b>Min.</b>	<b>Max.</b>	<b>Units</b>
Optical Output Power	$\Phi_e$	2.4		mW
Emission wavelength center of range $\Phi_e = 1 \text{ mW}$	$\lambda$	1280	1330	nm
Spectral bandwidth $\Phi_e = 1 \text{ mW}$ (RMS), $f < 5 \text{ GHz}$	$\Delta\lambda$		0.1	
Side mode suppression ratio	SSR	30		dB
Threshold current ( $0 \dots +70^\circ\text{C}$ )	$I_{\text{th}}$	5	55	mA
Forward voltage $\Phi_e = 1 \text{ mW}$	$V_F$		1.5	V
Radiant power at threshold	$\Phi_{\text{eth}}$		80	$\mu\text{W}$
Slope Efficiency ( $0 \dots +70^\circ\text{C}$ )	$\eta$	25	150	$\text{mW/A}$
Differential series resistance	$R_S$		8	$\Omega$
Rise and fall time	$t_R t_F$		0.5	ns
Temperature Coefficient of the emission wavelength center	$TC_\lambda$		0.15	nm/K
Optical Isolation ( $T=25^\circ\text{C}$ )		30		dB
<b>Monitor diode</b>				
Dark current, $V_R = 5 \text{ V}$ , $\Phi_e = 0$	$I_R$		500	nA
Photocurrent, $\Phi_e = 1 \text{ mW}$	$I_P$	100	1400	$\mu\text{A}$

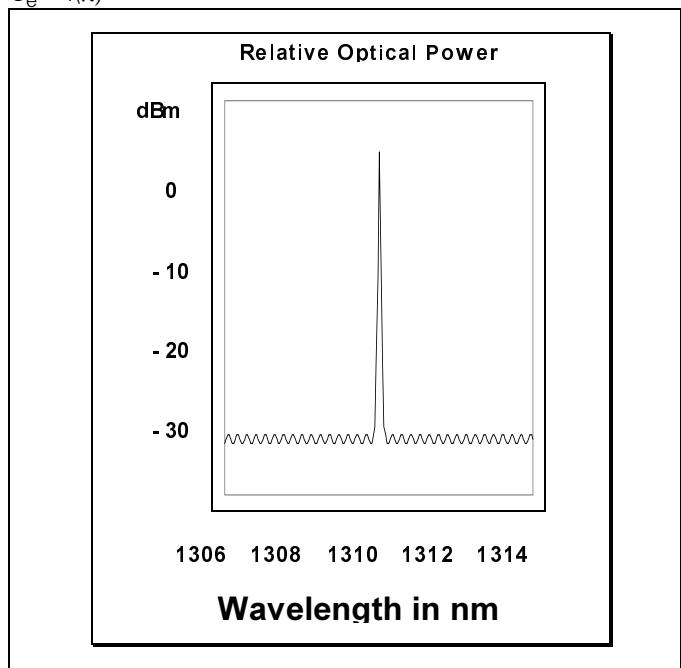
## Laser Diode

Radiant Power in Singlemode Fibre

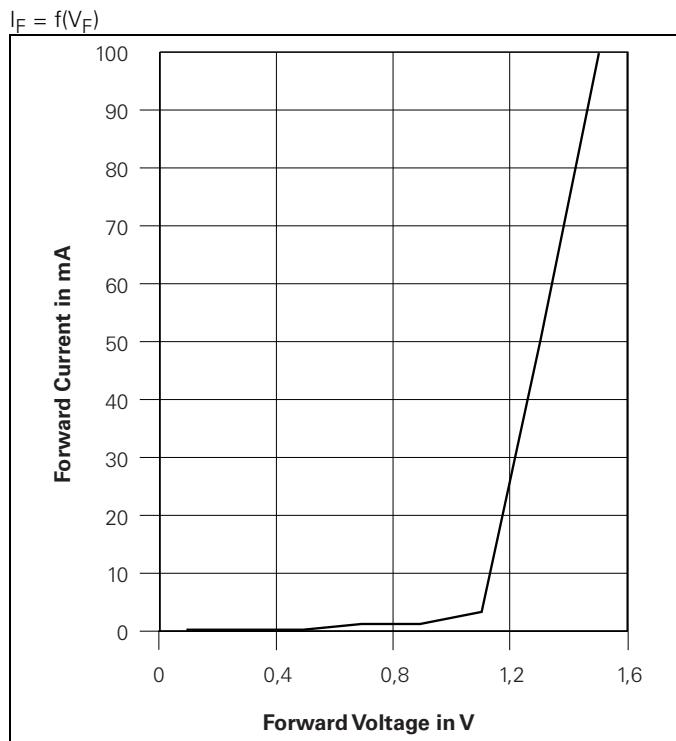


## Relative Radiant Power

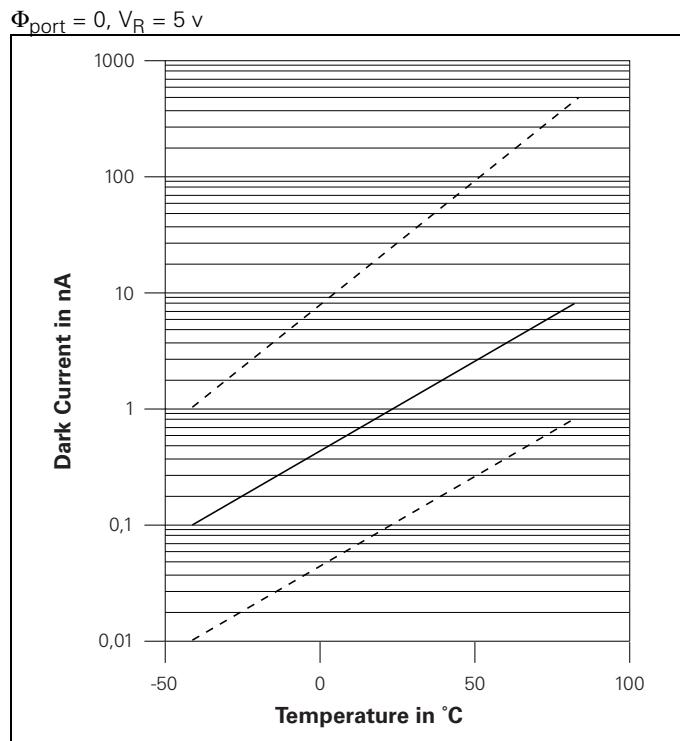
$\Phi_e = f(\lambda)$



### Laser Forward Current



### Monitor Diode Dark Current



Type	Connector/Flange
SDH61008G	FC / without flange
SDH61008A	DIN / without flange